

## Contents of Applied Physics A 52

This listing presents the papers in alphabetical order of the first author, subdivided into the sections "Solids and Materials: Physical and Chemical Properties" and "Surfaces and Multilayers: Growth, Modification, and Integration". The Author Index that follows covers **Applied Physics A** and **B**, and is presented in tabular form. The names are listed in alphabetical order in the first column. The second and third columns contain the bibliographic data necessary to locate the paper. The issue is specified by the number separated from the volume number by a slash. The PACS numbers given in the fourth column may be used in conjunction with the PACS listing on the left to infer the topic of a paper.

### Solids and Materials

- Ajiki K., Shimada D., Kido T., Miyakawa N., Tsuda N.:  
Tunneling conductance of a  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_8\text{-SnO}_2$  junction along the c-axis.  
Appl. Phys. A 52/1, 1-6 (1991) PACS: 74.50 74.70
- Al-Refaie S.N.:  
A generalized formula to determine the relaxation time distribution in dielectrics.  
Appl. Phys. A 52/4, 234-236 (1991) PACS: 73.40R 73.40 73.60
- Bronold M., Pettenkofer C., Jaegermann W.:  
Alkali metal intercalation into  $\text{SnS}_2$ . UHV investigations of (0001)-surfaces.  
Appl. Phys. A 52/3, 171-179 (1991) PACS: 68.65 79.60
- Catania M.F., Calcagno L., Coffa S., Campisano S.U., Raspagliesi M., Ferla G.:  
Compensating effects of platinum in n- and p-type silicon.  
Appl. Phys. A 52/2, 119-122 (1991) PACS: 66.30 72.80
- Consolati G., Quasso F.:  
The experimental determination of the qPs contact density in matter.  
Appl. Phys. A 52/5, 295-298 (1991) PACS: 36.10 71.60 78.70
- Dargys A., Zurauskas S., Zurauskienė N.:  
Transient tunneling spectroscopy (TTS) study of electron tunneling from phosphorus atoms in silicon.  
Appl. Phys. A 52/1, 13-18 (1991) PACS: 71.55 73.40 77.50
- Giakoumakis G.E.:  
Matching factors for various light-source-photodetector combinations.  
Appl. Phys. A 52/1, 7-9 (1991) PACS: 78.55 78.60 42.80
- Giber J., Drube R., Dose V.:  
Critical point energies in hcp and fcc cobalt from appearance potential spectra.  
Appl. Phys. A 52/2, 167-170 (1991) PACS: 73.20A 73.20
- Granqvist C.G.:  
Solar energy materials: Overview and some examples.  
Appl. Phys. A 52/2, 83-93 (1991) PACS: 01.30R 89.30 42.80 42.70
- Groza A.D., Strizhevskii V.L.:  
P-polarized nonlinear surface polaritons near the surface of a saturable self-defocusing medium: Threshold case.  
Appl. Phys. A 52/3, 180-183 (1991) PACS: 42.65B 42.85
- Hoheisel W., Vollmer M., Träger F.:  
Laser-stimulated desorption of potassium atoms.  
Appl. Phys. A 52/6, 445-447 (1991) PACS: 82.65 36.40 73.20
- Ibrahim M.M., Wakkad M.M., Shokr E.Kh., Abd El-Ghani H.A.:  
Electrical properties of antimony telluride.  
Appl. Phys. A 52/4, 237-241 (1991) PACS: 2.20
- JIANG Z., MA B.:  
Quasiperiodicity and chaos in the Gunn effect.  
Appl. Phys. A 52/1, 10-12 (1991) PACS: 72.20H 05.45
- Korpiun P., Osiander R., Schmitt H., Micheler W.:  
Heat and mass transport in the photoacoustic effect on liquids.  
Appl. Phys. A 52/4, 223-233 (1991) PACS: 44.25 44.60 47.25
- Kovács L., Moya E., Polgár K., López F.J., Zaldo C.:  
Photochromic behaviour of doped  $\text{Bi}_4\text{Ge}_3\text{O}_{12}$  single crystal scintillators.  
Appl. Phys. A 52/3, 307-312 (1991) PACS: 61.80 78.50 76.30
- Liu J., Weppner W.:  
Limiting-current type surface modified gas sensor based on  $\beta^+$ -alumina fast solid ionic conductor.  
Appl. Phys. A 52/2, 94-99 (1991) PACS: 66.30 82.45 82.80 85.80
- Lu H., Bao C.L., Xue Q.K., Tang D.S.:  
Clustering effect in crystallization process of a CuZr amorphous alloy.  
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- Mari B., Segura A., Casanovas A., Chevy A.:  
Deep-level transient spectroscopy measurement on tin-doped n-indium selenide.  
Appl. Phys. A 52/6, 373-379 (1991) PACS: 71.55
- Marinelli M., Mercuri F., Zammit U., Pizzoferrato R.:  
The influence of the coupling fluids and of the pyroelectric transducer on low-temperature photopyroelectric studies.  
Appl. Phys. A 52/2, 115-118 (1991) PACS: 78.20H
- Mitev A.P., Strashinov V.L., Burov J.I.:  
A direct method for measuring the temperature coefficients of bulk acoustic velocities in crystals.  
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- Nikogosyan D.N.:  
Beta barium borate (BBO). A review of its properties and applications.  
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Simultaneous measurement of thermal diffusivity, thermal conductivity and specific heat by impulse-response photopyroelectric spectrometry.  
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- Petrocelli G., Scudieri F., Martellucci S.:  
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Individual, attractive defect centers in the  $\text{SiO}_2$ -Si interface of  $\mu\text{m}$ -sized MOSFETs.  
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Two-dimensional melting of physisorbed submonolayers of argon and nitrogen. A positron annihilation study.  
Appl. Phys. A 52/4, 247-254 (1991) PACS: 78.70B 36.10 71.60
- Slavov S.:  
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- Tendeloo G.van, Amelinckx S.:  
Long-period shear structure in lanthanum cuprate.  
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Spatio-temporal structure formation and self-diffraction in CdS using laser-induced thermal gratings.  
Appl. Phys. A 52/4, 255-260 (1991) PACS: 78.20N 42.65
- Torres R., Francisco C.de, Munoz J.M.:  
Magnetic disaccommodation in normal spinel structures.  
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- Zammit U., Gasparrini F., Marinelli M., Pizzoferrato R., Scudieri F., Martellucci S.:  
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Explanation for TEM<sub>00</sub> operation of heavily doped  $\text{YAlO}_3\text{:Er}^{3+}$ .  
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A study of the density of gap states in amorphous semiconductors from thermally stimulated conductivity spectra.  
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### Surfaces and Multilayers

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Laser-induced mixing and microstructures in GeAl thin multilayer films.  
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- Amato G., Benedetto G., Boarino L., Maringelli M., Spagnolo R.:  
Influence of substrate in photothermal measurements of thin film absorption.  
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- Annino A., Lo Savio M., Oliveri M.E.:  
Spray method: Dependence of deposition efficiency on substrate temperature.  
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- Bagratashvili V.N., Banishev A.F., Gnedov S.A., Emelyanov V.I., Jerikhin A.N., Merzljakov K.S., Panchenko V.Ya., Seminogov V.N.:  
The formation of periodic ring structures of relief and voids under laser vapor deposition of the metallic films.  
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Study of hydrogenated amorphous silicon nitride films prepared by RF magnetron sputtering.  
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Ultraviolet photoablation of a plasma-synthesized fluorocarbon polymer.  
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Optical emission diagnostics of laser-induced plasma for diamond-like film deposition.  
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Optical properties of CdIn<sub>2</sub>Se<sub>4</sub> thin films.  
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Dielectric and pyroelectric properties of Langmuir-Blodgett film capacitors.  
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Analysis of reflectance data using the Kramers-Kronig relations.  
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Oxidation state of Fe and Ti ions implanted in yttria-stabilized zirconia studied by XPS.  
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Excimer laser surface treatment of bulk ceramics.  
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